

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

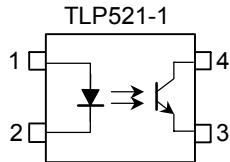
# TLP521-1, TLP521-2, TLP521-4

Programmable Controllers  
 AC/DC-Input Module  
 Solid State Relay

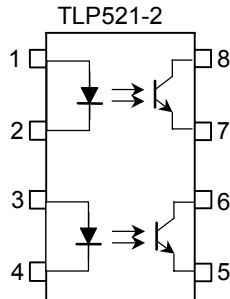
The TOSHIBA TLP521-1, -2 and -4 consist of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode. The TLP521-2 offers two isolated channels in an eight lead plastic DIP package, while the TLP521-4 provides four isolated channels in a sixteen plastic DIP package.

- Collector-emitter voltage: 55 V (min)
- Current transfer ratio: 50% (min)  
 Rank GB: 100% (min)
- Isolation voltage: 2500 Vrms (min)
- UL recognized  
 made in Japan: UL1577, file No. E67349  
 made in Thailand: UL1577, file No. E152349

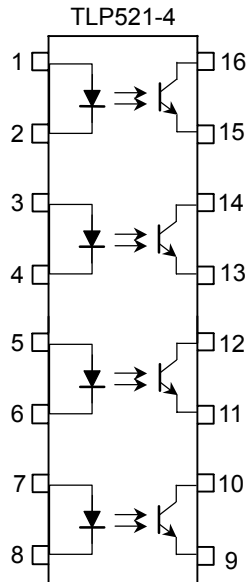
### Pin Configurations (top view)



1 : Anode  
 2 : Cathode  
 3 : Emitter  
 4 : Collector

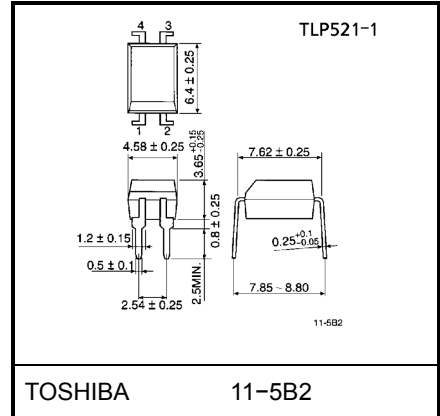


1, 3 : Anode  
 2, 4 : Cathode  
 5, 7 : Emitter  
 6, 8 : Collector

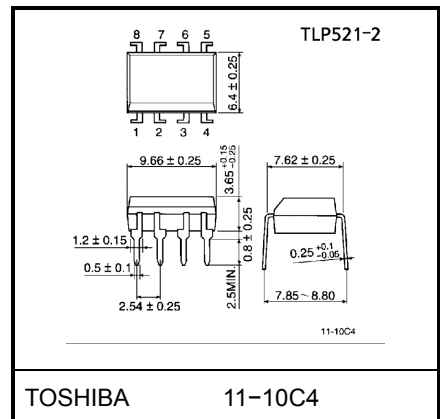


1, 3, 5, 7 : Anode  
 2, 4, 6, 8 : Cathode  
 9, 11, 13, 15 : Emitter  
 10, 12, 14, 16 : Collector

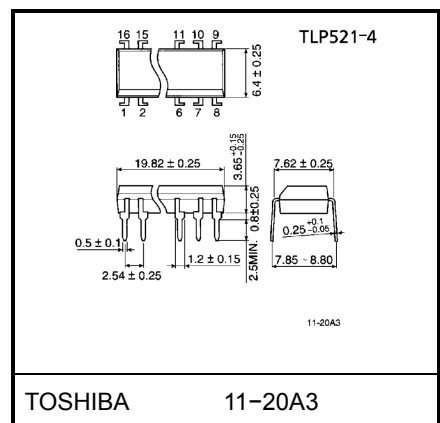
Unit in mm



TOSHIBA 11-5B2  
 Weight: 0.26 g



TOSHIBA 11-10C4  
 Weight: 0.54 g



TOSHIBA 11-20A3  
 Weight: 1.1 g

## Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating		Unit
			TLP521-1	TLP521-2 TLP521-4	
LED	Forward current	$I_F$	70	50	mA
	Forward current derating	$\Delta I_F / ^\circ\text{C}$	-0.93 (Ta ≥ 50°C)	-0.5 (Ta ≥ 25°C)	mA / °C
	Pulse forward current	$I_{FP}$	1 (100μ pulse, 100pps)		A
	Reverse voltage	$V_R$	5		V
	Junction temperature	$T_j$	125		°C
Detector	Collector-emitter voltage	$V_{CEO}$	55		V
	Emitter-collector voltage	$V_{ECO}$	7		V
	Collector current	$I_C$	50		mA
	Collector power dissipation (1 circuit)	$P_C$	150	100	mW
	Collector power dissipation derating (1 circuit Ta ≥ 25°C)	$\Delta P_C / ^\circ\text{C}$	-1.5	-1.0	mW / °C
	Junction temperature	$T_j$	125		°C
Storage temperature range		$T_{stg}$	-55~125		°C
Operating temperature range		$T_{opr}$	-55~100		°C
Lead soldering temperature		$T_{sol}$	260 (10 s)		°C
Total package power dissipation		$P_T$	250	150	mW
Total package power dissipation derating (Ta ≥ 25°C)		$\Delta P_T / ^\circ\text{C}$	-2.5	-1.5	mW / °C
Isolation voltage		$BV_S$	2500 (AC, 1min., R.H. ≤ 60%) (Note 1)		Vrms

(Note 1): Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

## Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Supply voltage	$V_{CC}$	—	5	24	V
Forward current	$I_F$	—	16	25	mA
Collector current	$I_C$	—	1	10	mA
Operating temperature	$T_{opr}$	-25	—	85	°C

Type	Classi- fication (*1)	Current Transfer Ratio (%) ( $I_C / I_F$ )		Marking Of Classification
		$I_F = 5\text{mA}, V_{CE} = 5\text{V}, T_a = 25^\circ\text{C}$		
		Min	Max	
TLP521	A	50	600	Blank, Y, Y <sup>■</sup> , G, G <sup>■</sup> , B, B <sup>■</sup> , GB
	Rank Y	50	150	Y, Y <sup>■</sup>
	Rank GR	100	300	G, G <sup>■</sup>
	Rank BL	200	600	B, B <sup>■</sup>
	Rank GB	100	600	G, G <sup>■</sup> , B, B <sup>■</sup> , GB
TLP521-2 TLP521-4	A	50	600	Blank, GR, BL, GB
	Rank GB	100	600	GR, BL, GB

\*1: Ex. rank GB: TLP521-1 (GB)

(Note): Application type name for certification test, please use standard product type name, i.e.

TLP521-1 (GB): TLP521-1, TLP521-2 (GB): TLP521-2

## Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	$V_F$	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	$I_R$	$V_R = 5 \text{ V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 0.5 \text{ mA}$	55	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR)ECO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector dark current	$I_{CEO}$	$V_{CE} = 24 \text{ V}$	—	10	100	nA
			$V_{CE} = 24 \text{ V}, T_a = 85^\circ\text{C}$	—	2	50	$\mu\text{A}$
Capacitance (collector to emitter)	$C_{CE}$	$V = 0, f = 1 \text{ MHz}$	—	10	—	pF	

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	$I_C / I_F$	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$ Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	$I_C / I_F (\text{sat})$	$I_F = 1 \text{ mA}, V_{CE} = 0.4 \text{ V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	$V_{CE (\text{sat})}$	$I_C = 2.4 \text{ mA}, I_F = 8 \text{ mA}$	—	—	0.4	V
		$I_C = 0.2 \text{ mA}, I_F = 1 \text{ mA}$ Rank GB	—	0.2	—	
			—	—	0.4	

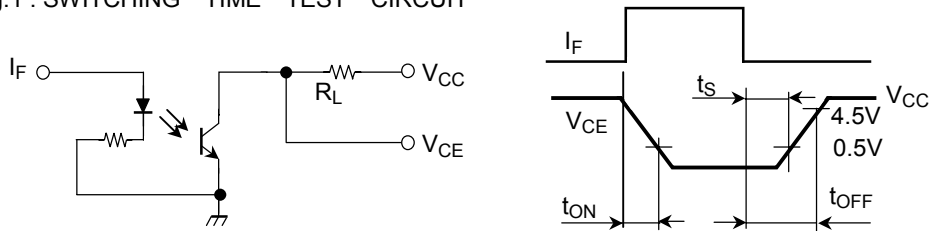
## Isolation Characteristics (Ta = 25°C)

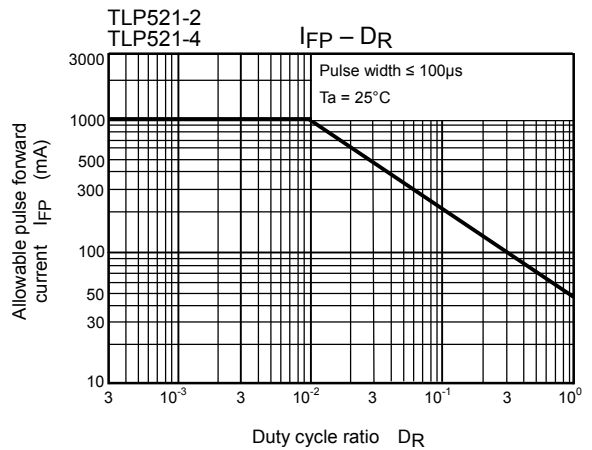
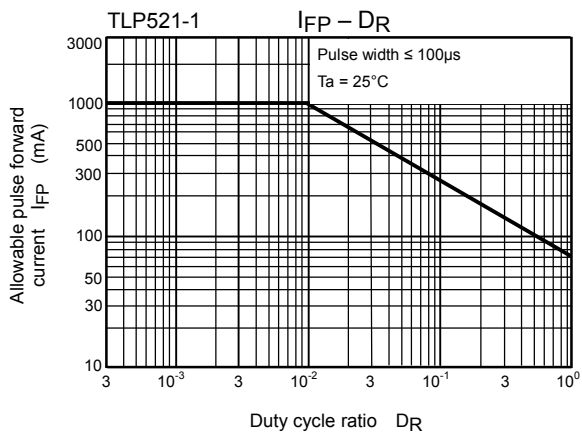
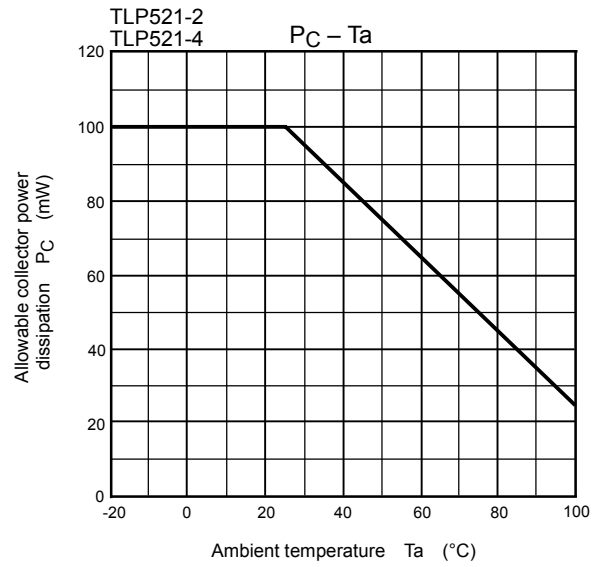
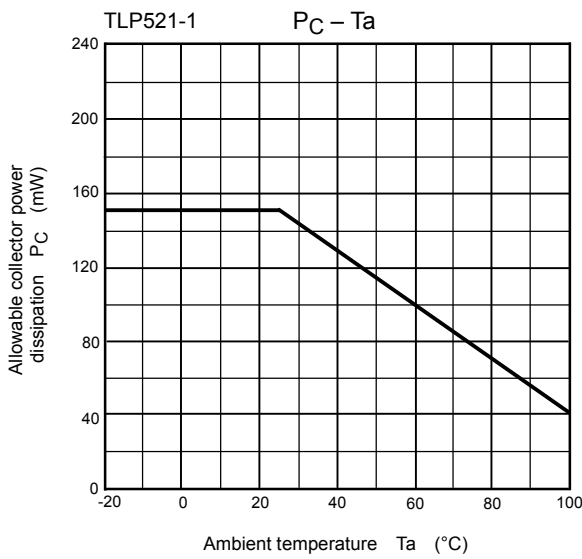
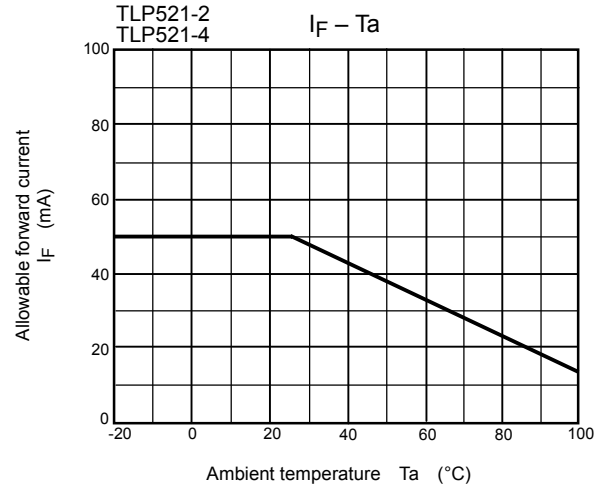
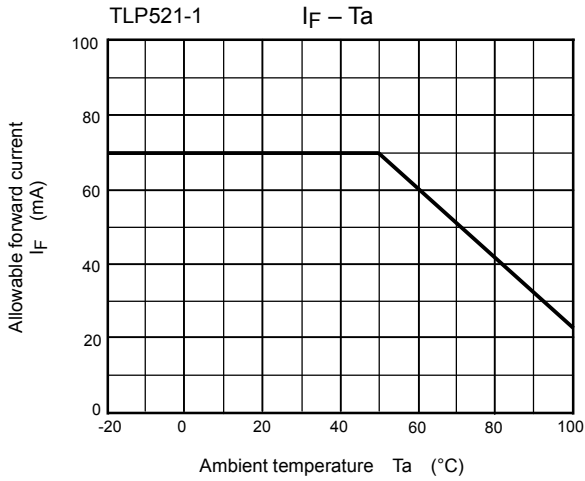
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance (input to output)	$C_S$	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	$R_S$	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	—	$10^{11}$	—	$\Omega$
Isolation voltage	$BV_S$	AC, 1 minute	2500	—	—	Vrms
		AC, 1 second, in oil	—	5000	—	
		DC, 1 minute, in oil	—	5000	—	Vdc

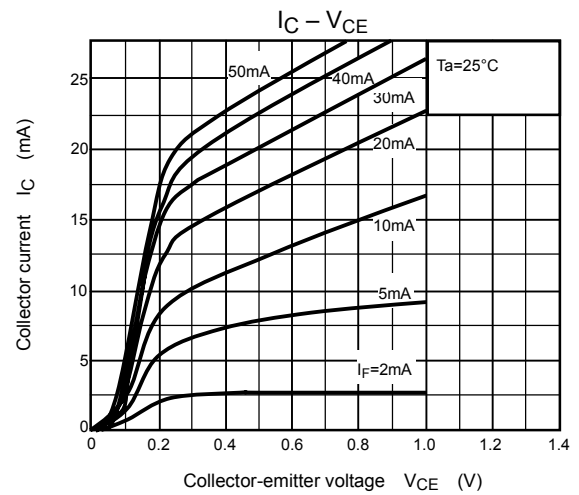
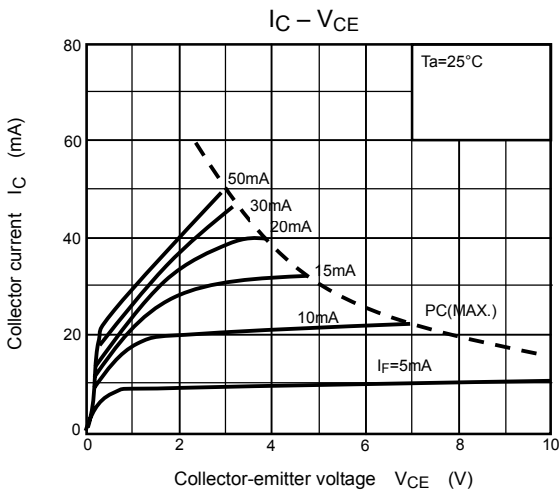
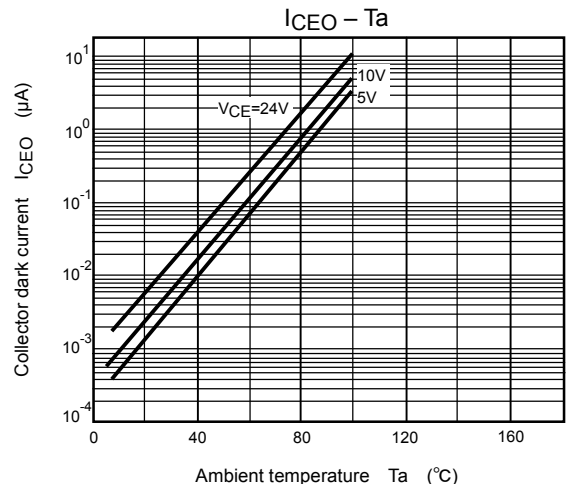
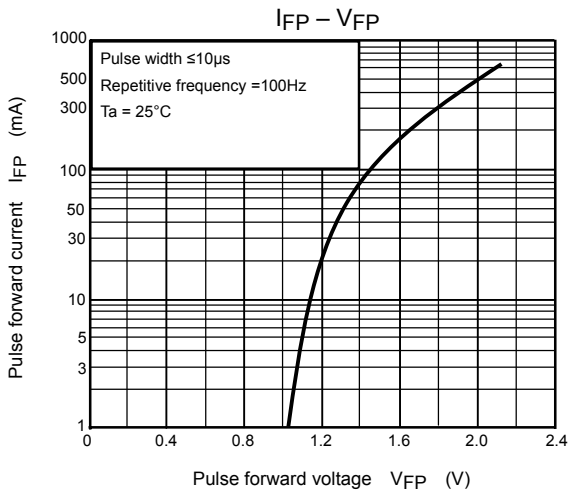
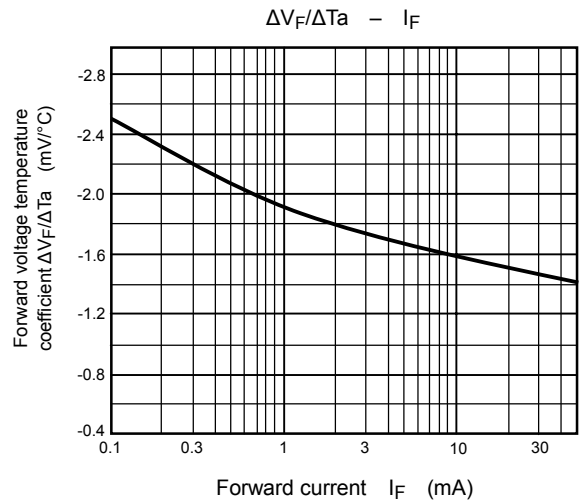
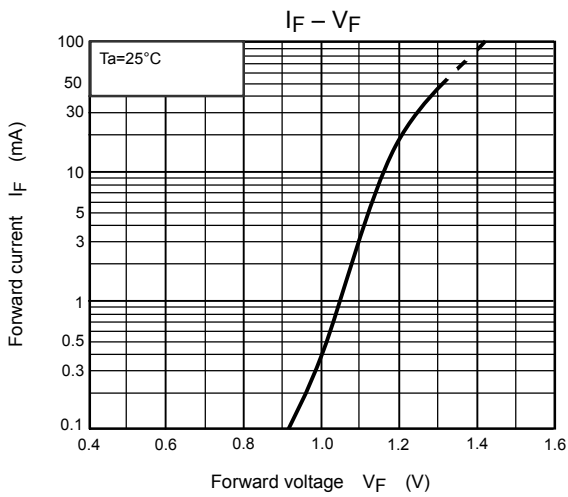
## Switching Characteristics (Ta = 25°C)

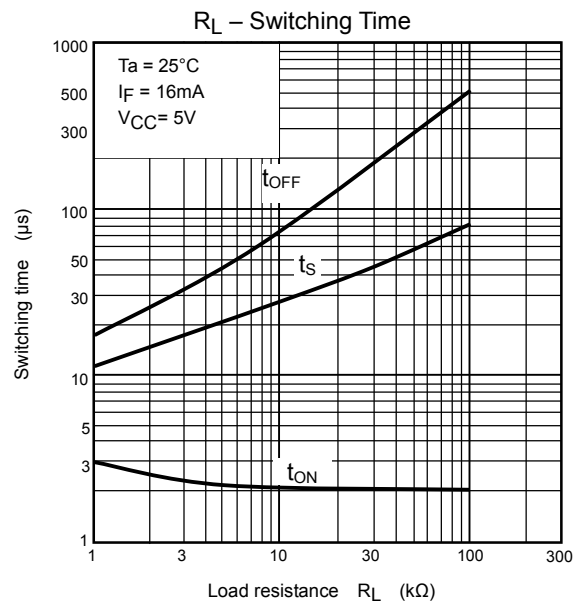
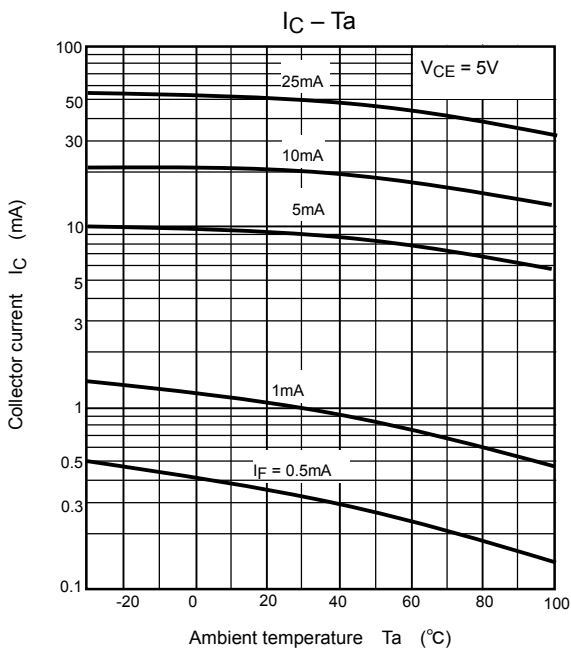
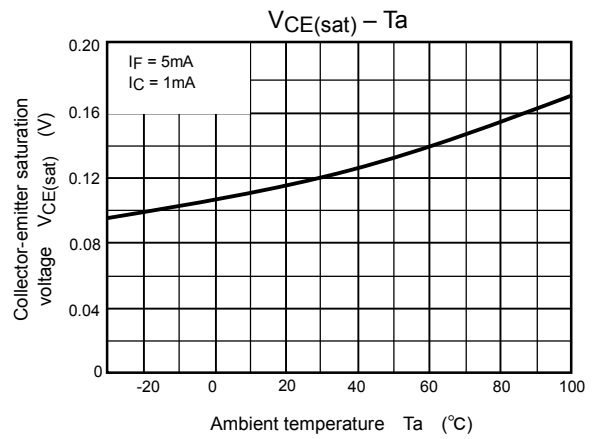
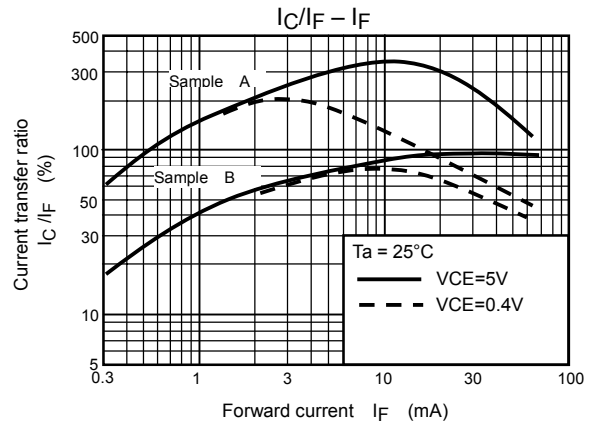
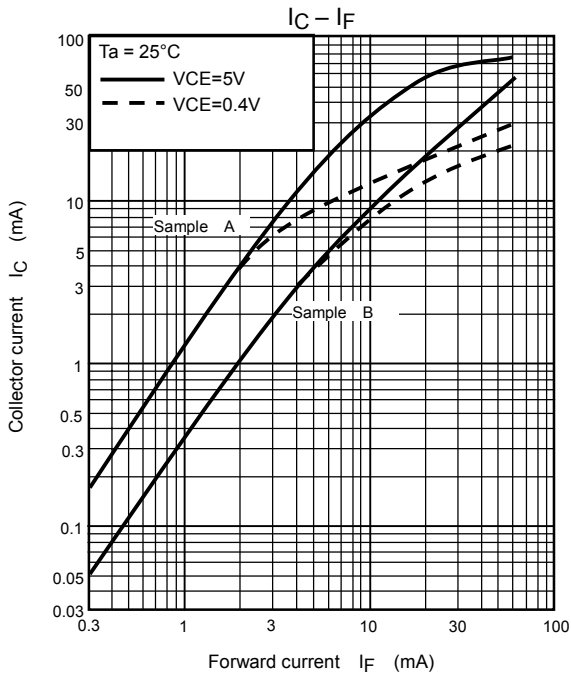
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Rise time	$t_r$	$V_{CC} = 10\text{ V}$ $I_C = 2\text{ mA}$ $R_L = 100\Omega$	—	2	—	$\mu\text{s}$
Fall time	$t_f$		—	3	—	
Turn-on time	$t_{on}$		—	3	—	
Turn-off time	$t_{off}$		—	3	—	
Turn-on time	$t_{ON}$	$R_L = 1.9\text{ k}\Omega$ (Fig.1) $V_{CC} = 5\text{ V}$ , $I_F = 16\text{ mA}$	—	2	—	$\mu\text{s}$
Storage time	$t_s$		—	15	—	
Turn-off time	$t_{OFF}$		—	25	—	

Fig.1 : SWITCHING TIME TEST CIRCUIT











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000707EBC

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